

MOS FIELD EFFECT TRANSISTOR  
**2SK1485**

**N-CHANNEL MOS FIELD EFFECT TRANSISTOR  
 FOR SWITCHING**

**DESCRIPTION**

The 2SK1485, N-channel vertical type MOS FET is a switching device which can be driven directly by the output of ICs having a 5 V power source. As the MOS FET has low on-state resistance and excellent switching characteristics, it is suitable for driving actuators such as motors, relays, and solenoids.

**FEATURES**

- Directly driven by ICs having a 5 V power source.
- Low on-state resistance  
 $R_{DS(on)1} = 1.2 \Omega \text{ MAX. (} V_{GS} = 4.0 \text{ V, } I_D = 0.5 \text{ A)}$   
 $R_{DS(on)2} = 0.8 \Omega \text{ MAX. (} V_{GS} = 10 \text{ V, } I_D = 0.5 \text{ A)}$
- Complementary to 2SJ199.

**ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C)**

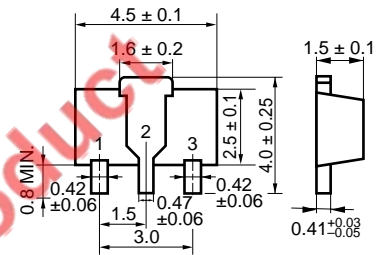
Drain to Source Voltage (V <sub>GS</sub> = 0 V)	V <sub>DSS</sub>	100	V
Gate to Source Voltage (V <sub>DS</sub> = 0 V)	V <sub>GSS</sub>	±20	V
★ Drain Current (DC) (T <sub>c</sub> = 25°C)	I <sub>D(DC)</sub>	±1.0	A
Drain Current (pulse) <sup>Note1</sup>	I <sub>D(pulse)</sub>	±2.0	A
Total Power Dissipation (T <sub>A</sub> = 25°C) <sup>Note2</sup>	P <sub>T</sub>	2.0	W
Channel Temperature	T <sub>ch</sub>	150	°C
Storage Temperature	T <sub>stg</sub>	-55 to +150	°C

**Notes1.** PW ≤ 10 ms, Duty Cycle ≤ 50%

**2.** Mounted on ceramic board of 16 cm<sup>2</sup> × 0.7 mm

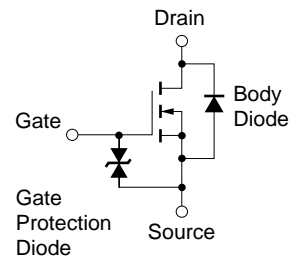
**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

**PACKAGE DRAWING (Unit : mm)**



1. Source  
 2. Drain  
 3. Gate  
 MARK : NC

**EQUIVALENT CIRCUIT**

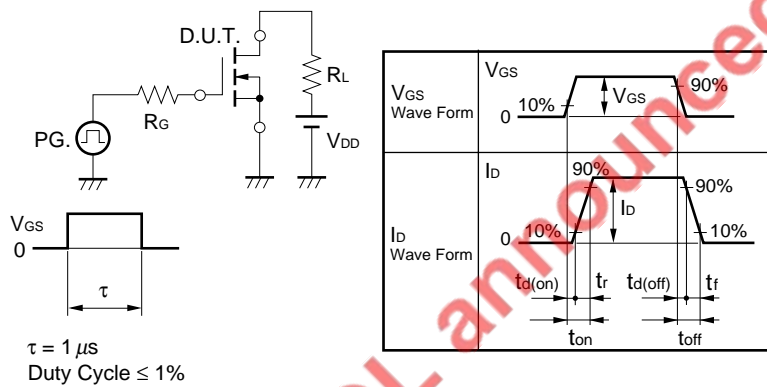


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**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)**

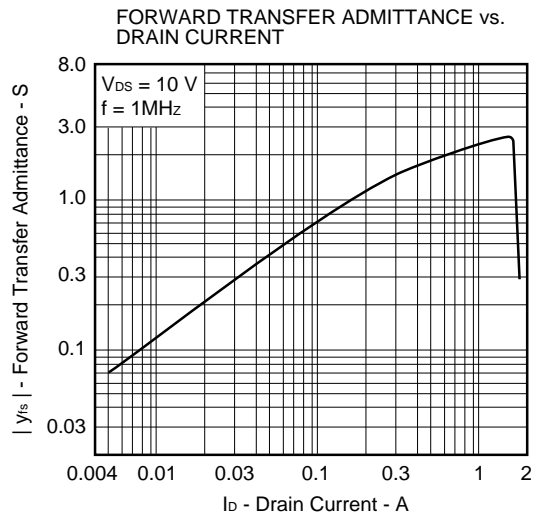
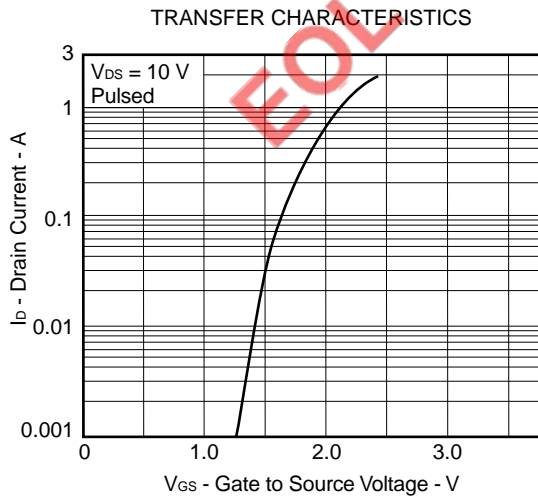
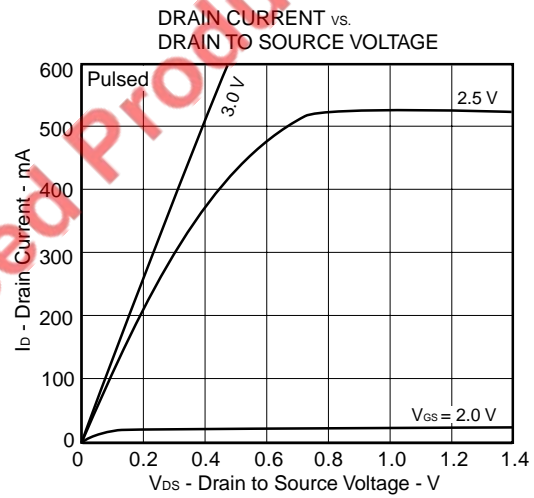
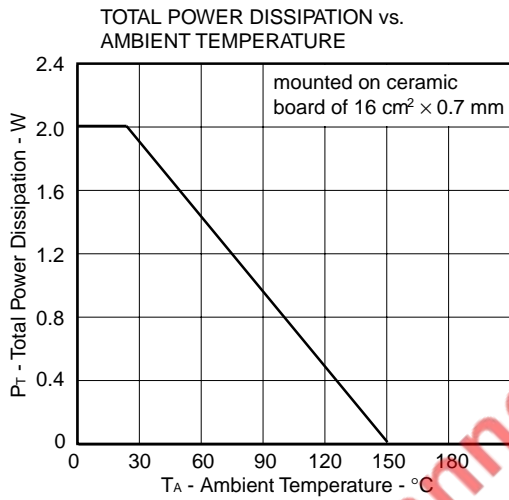
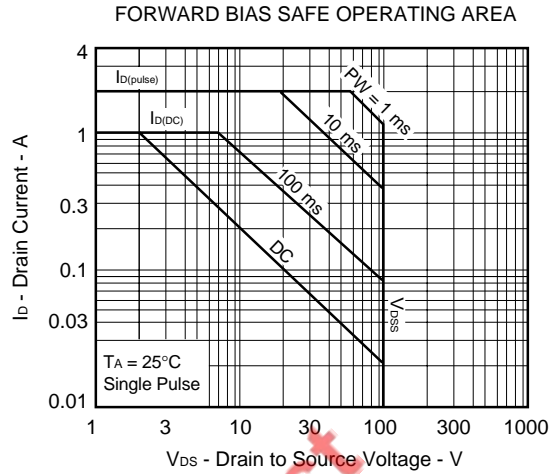
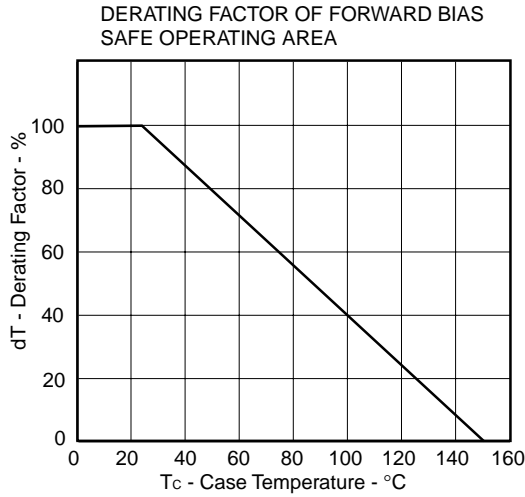
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 100 V, V <sub>GS</sub> = 0 V			10	μA
Gate Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0 V			±10	μA
Gate Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	0.8	1.2	2.0	V
Forward Transfer Admittance	y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 0.5 A	0.4			S
Drain to Source On-state Resistance	R <sub>DS(on)1</sub>	V <sub>GS</sub> = 4.0 V, I <sub>D</sub> = 0.5 A		0.6	1.2	Ω
	R <sub>DS(on)2</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 0.5 A		0.5	0.8	Ω
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 10 V		230		pF
Output Capacitance	C <sub>OSS</sub>	V <sub>GS</sub> = 0 V		80		pF
Reverse Transfer Capacitance	C <sub>rss</sub>	f = 1 MHz		12		pF
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> = 25 V, I <sub>D</sub> = 0.5 A		14		ns
Rise Time	t <sub>r</sub>	V <sub>GS</sub> = 10 V		14		ns
Turn-off Delay Time	t <sub>d(off)</sub>	R <sub>G</sub> = 10 Ω		370		ns
Fall Time	t <sub>f</sub>			65		ns

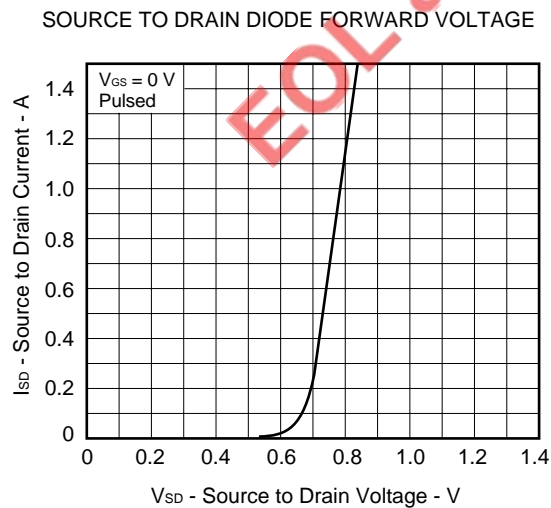
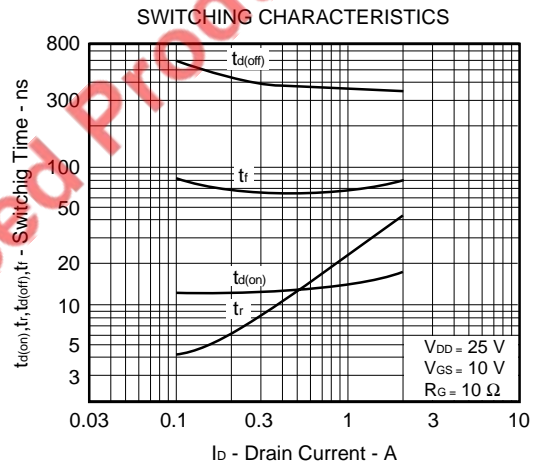
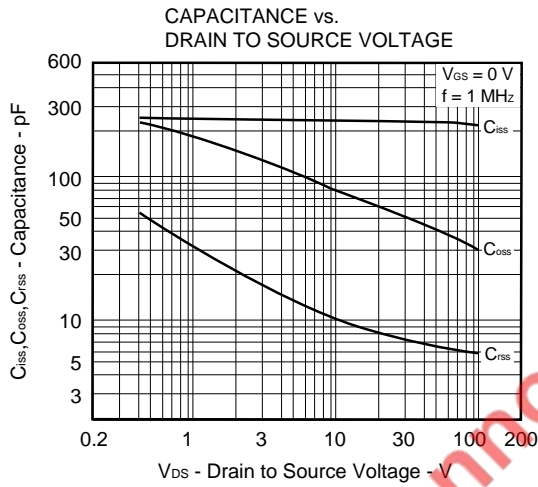
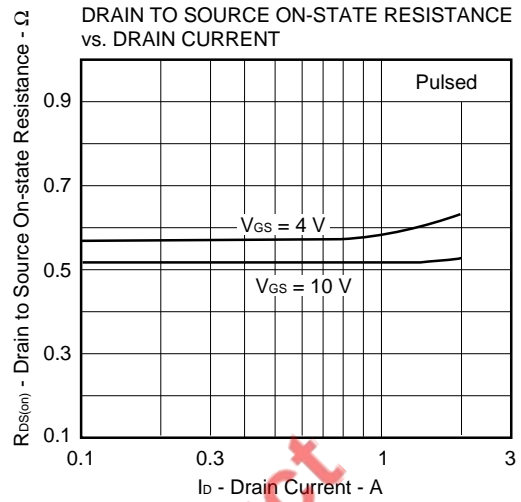
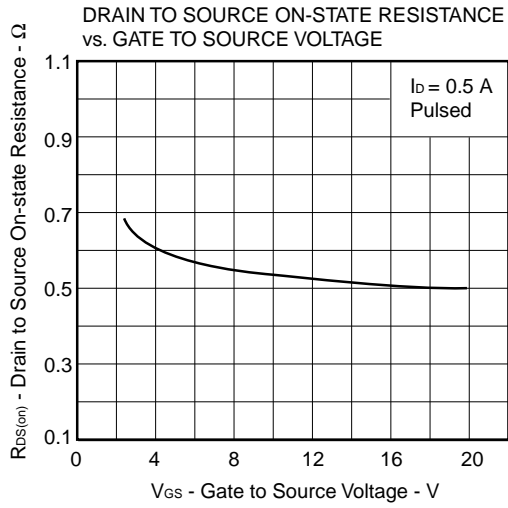
**SWITCHING TIME**



EOL announced Product

TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)





[MEMO]

**EOL announced Product**

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**EOL announced Product**

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**EOL announced Product**

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